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WHAT IS CLAIMED IS:

1. A reflecting layer comprising:

Ag as a main component;

a 0.1-3.0 wt% first element selected from the group consisting of Au, Pd, and Ru; and

a 0.1-3.0 wt% second element selected from the group consisting of Cu, Ti, Cr, Ta, Mo, Ni, Al, Nb, Au, Pd, and Ru, wherein the second element is different from the first element.

- 2. The reflecting layer according to claim 1, wherein the reflecting layer is formed by deposition.
- 15 3. The reflecting layer according to claim 1, wherein the reflecting layer is formed by sputtering.
 - 4. A laminate comprising:
 - a substrate; and
- a reflecting layer deposited on the substrate, wherein the reflecting layer includes Ag as a main component, a 0.1-3.0 wt% first element selected from the group consisting of Au, Pd, and Ru, and a 0.1-3.0 wt% second element selected from the group consisting of Cu,
- 25 Ti, Cr, Ta, Mo, Ni, Al, Nb, Au, Pd, and Ru, wherein the second element is different from the first element.
 - 5. The laminate according to claim 4, wherein the substrate is a resin substrate.
 - 6. The laminate according to claim 4, wherein the substrate is a glass substrate.
 - 7. A laminate comprising:
- 35 a substrate;

a base film deposited on the substrate, wherein the base film is made of at least one of Si, Ta, Ti, Mo, Cr, Al, ITO, $\rm ZnO_2$, $\rm SiO_2$, $\rm TiO_2$, $\rm Ta_2O_5$, $\rm ZrO_2$, $\rm In_2O_3$, $\rm SnO_2$, $\rm Nb_2O_5$, or MgO; and

- 5 an Ag-containing reflecting layer deposited on the base film.
 - 8. The laminate according to claim 7, wherein the reflecting layer includes pure Ag or binary Ag alloy.
- 9. The laminate according to claim 7, wherein the reflecting layer includes Ag as a main component, a 0.1-3.0 wt% first element selected from the group consisting of Au, Pd, and Ru, and a 0.1-3.0 wt% second element selected from the group consisting of Cu, Ti, Cr, Ta, Mo, Ni, Al, Nb, Au, Pd, and Ru, wherein the second element is different from the first element.
- 10. The laminate according to claim 7 further comprising a coating layer/deposited on the reflecting layer, wherein the coating layer includes In_2O_3 as a main component and at least one of SnO_2 , Nb_2O_5 , SiO_2 , MgO and Ta_2O_5 .
- 11. The laminate according to claim 7, wherein the substrate is a glass substrate.
 - 12. The laminate according to claim 7, wherein the base film is made of at least one of Si, Ta, Ti, Mo, Cr, or Al.
- 30 13. The laminate according to claim 7, wherein the base film is made of at least one of ITO, $\rm ZnO_2$, $\rm SiO_2$, $\rm TiO_2$, $\rm Ta_2O_5$, $\rm ZrO_2$, $\rm In_2O_3$, $\rm SnO_2$, $\rm Nb_2O_5$, or MgO.
- 14. The laminate according to claim 13, wherein the substrate is a resin substrate.

15. A laminate comprising:

an Ag-containing reflecting layer; and a coating layer deposited on the reflecting layer, wherein the coating layer includes In_2O_3 as a main component and at least one of SnO_2 , Nb_2O_5 , SiO_2 , MgO, and Ta_2O_5

- 16. The laminate according to claim 15, wherein the reflecting layer includes pure Ag or binary Ag alloy.
 - 17. The laminate according to claim 15, wherein the reflecting layer includes Ag as a main component, a 0.1-3.0 wt% first element selected form the group consisting of Au, Pd, and Ru, and a 0.1-3.0 wt% second element selected from the group consisting of Cu, Ti, Cr, Ta, Mo, Ni, Al, Nb, Au, Pd, and Ru, wherein the second element is different from the first element.
- 20 18. The laminate according to claim 4, wherein the laminate is building glass or a reflector or a reflective wiring electrode for a liquid crystal display device.
- 19. The laminate according to claim 7, wherein the 25 laminate is building glass or a reflector or a reflective wiring electrode for a liquid crystal display device.
- 20. The laminate according to claim 10, wherein the laminate is building glass or a reflector or a reflective 30 wiring electrode for a liquid crystal display device.
 - 21. The laminate according to claim 15, wherein the laminate is building glass or a reflector or a reflective wiring electrode for a liquid crystal display device.

- 22. A liquid crystal display device comprising a reflecting layer, wherein the reflecting layer includes Ag as a main component, a 0.1-3.0 wt% first element selected from the group consisting of Au, Pd, and Ru, and a 0.1-3.0 wt% second element selected from the group consisting of Cu, Ti, Cr, Ta, Mo, Ni, Al, Nb, Au, Pd, and Ru, wherein the second element is different from the first element.
- 23. A liquid crystal display device comprising a laminate, wherein the laminate includes a substrate, a base film deposited on the substrate, and an Ag-containing reflecting layer deposited on the base film, wherein the base film is made of at least one of Si, Ta, Ti, Mo, Cr, Al, ITO, ZnO₂, SiO₂, TiO₂, Ta₂O₅, ZrO₂, In₂O₃, SnO₂, Nb₂O₅, or MgO.
- 24. The liquid crystal display device according claim 23, wherein the laminate further includes a coating layer deposited on the reflecting layer, wherein the coating
 20 layer includes In₂O₃ as a main component and at least one of SnO₂, Nb₂O₅, SiO₂, MgO and Ta₂O₅.
 - 25. A liquid crystal display device comprising a laminate, wherein the laminate includes an Ag-containing reflecting
- layer and a coating layer deposited on the reflecting layer, wherein the coating layer includes ${\rm In}_2{\rm O}_3$ as a main component and at least one of ${\rm SnO}_2$, ${\rm Nb}_2{\rm O}_5$, ${\rm SiO}_2$, ${\rm MgO}$, and ${\rm Ta}_2{\rm O}_5$.
- 26. A portable terminal device comprising a liquid crystal display device having a reflecting layer, wherein the reflecting layer includes Ag as a main component, a 0.1-3.0 wt% first element selected from the group consisting of Au, Pd, and Ru, and a 0.1-3.0 wt% second element
- 35 selected from the group consisting of Cu, Ti, Cr, Ta, Mo,

Ni, Al, Nb, Au, Pd, and Ru, wherein the second element is different from the first element.

- 27. A portable terminal device comprising a liquid crystal display device having a laminate, wherein the laminate includes a substrate, a base film deposited on the substrate, and an Ag-containing reflecting layer deposited on the base film, wherein the base film is made of at least one of Si, Ta, Ti, Mo, Cr, Al, ITO, ZnO₂, SiO₂, TiO₂, Ta₂O₅, ZrO₂, In₂O₃, SnO₂, Nb₂O₅, or MgO.
 - 28. The portable terminal device according claim 27, wherein the laminate further includes a coating layer deposited on the reflecting layer, wherein the coating layer includes In_2O_3 as a main component and at least one of SnO_2 , Nb_2O_5 , SiO_2 , MgO and Ta_2O_5 .
- 29. A portable terminal device comprising a liquid crystal display device having a laminate, wherein the laminate includes an Ag-containing reflecting layer and a coating layer deposited on the reflecting layer, wherein the coating layer includes In₂O₃ as a main component and at least one of SnO₂, Nb₂O₅, SiO₂, MgO, and Ta₂O₅.